

OKI Semiconductor

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MR27V3202D

2,097,152-Word x 16-Bit or 4,194,304-Word x 8-Bit
Production Programmed Read Only Memory (P2ROM)

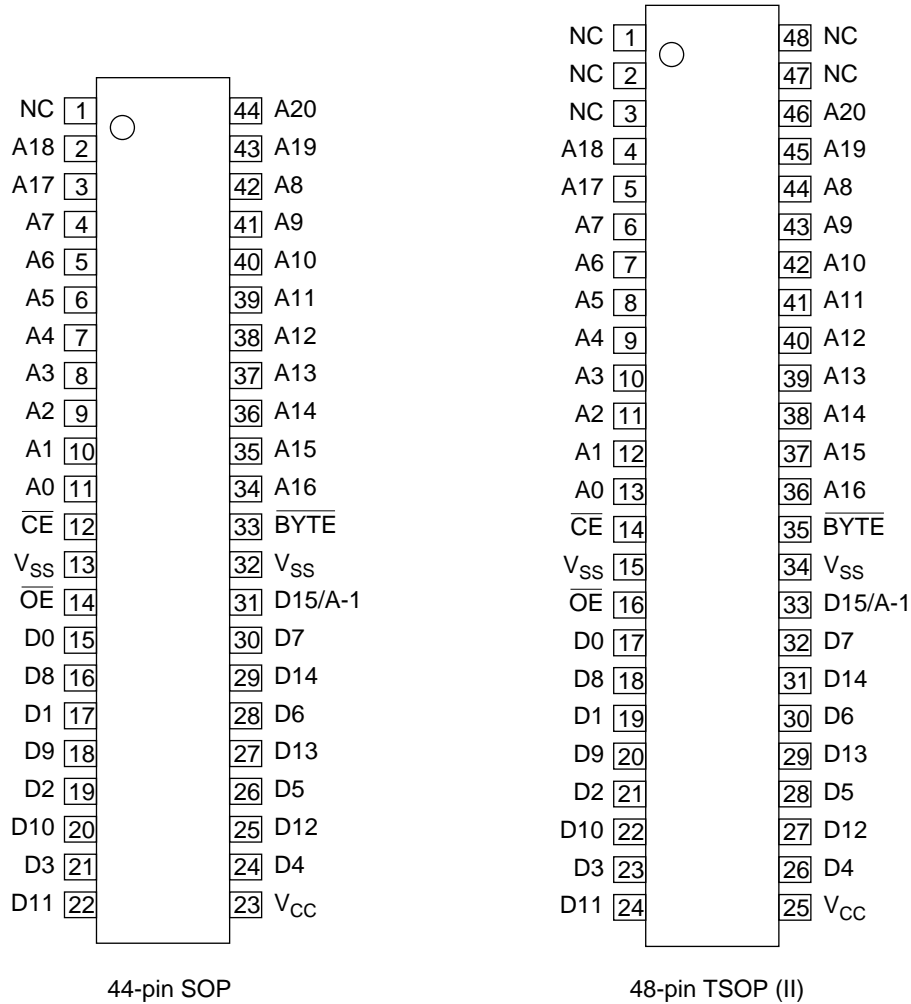
DESCRIPTION

The MR27V3202D is a 32Mbit Production Programmed Read-Only Memory (P2ROM) whose configuration can be electrically switched between 2,097,152 word x 16bit and 4,194,304 word x 8 bit. The MR27V3202D operates on a single +3V-3.3V power supply and is TTL compatible. Since the MR27V3202D operates asynchronously, external clocks are not required, making this device easy-to-use. The MR27V3202D is suitable as large-capacity fixed memory for microcomputers and data terminals. It is manufactured using a CMOS double silicon gate technology and is offered in 44-pin SOP or 48-pin TSOP packages.

FEATURES

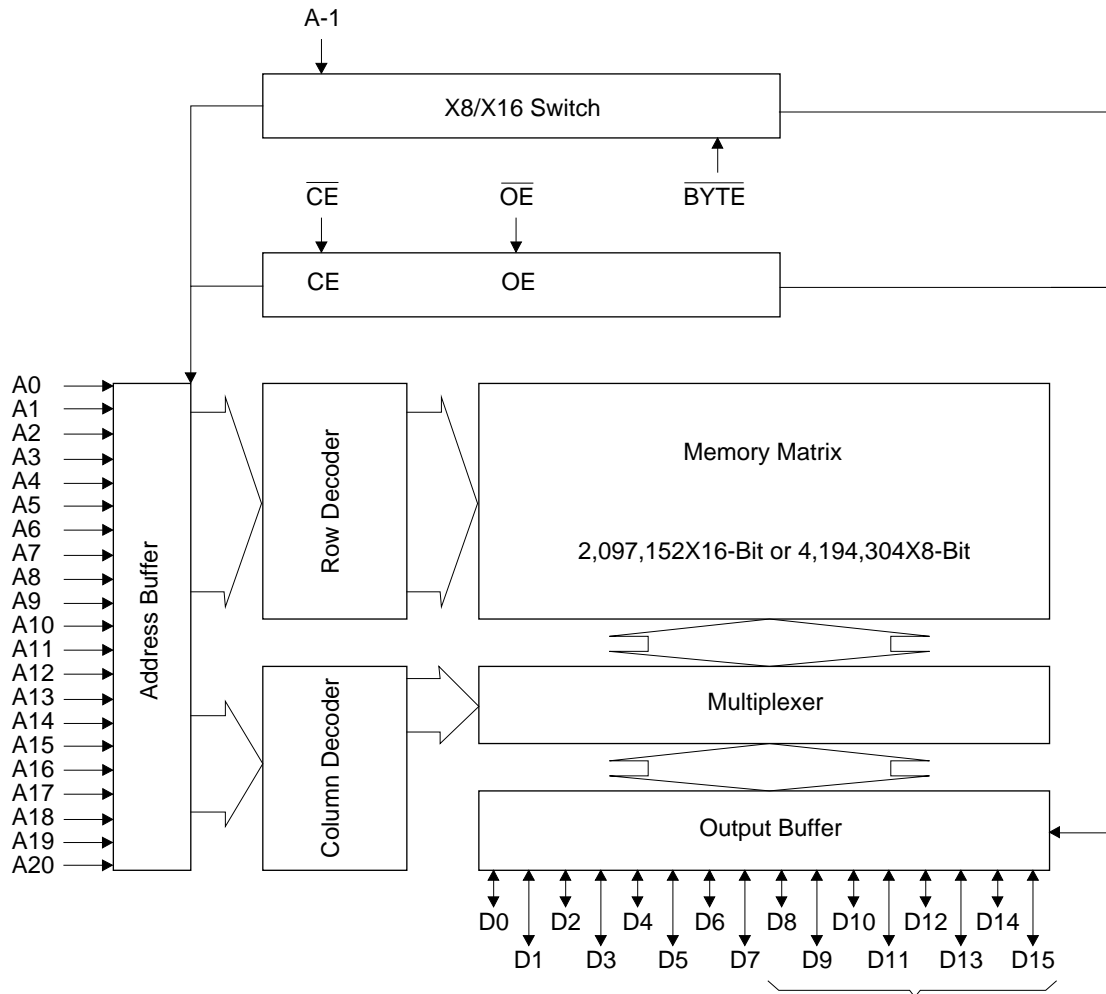
- 2,097,152 word x 16bit / 4,194,304 word x 8bit electrically switchable configuration
- Single +3V-3.3V power supply
- Access time 120ns access time (Vcc=+3V)
 100ns access time (Vcc=+3.3V)
- Input / Output TTL compatible
- Three-state output
- Packages
 44-pin plastic SOP (SOP44-P-600-1.27-K) (Product name : MR27V3202D-xxMA)
 48-pin plastic TSOP (TSOP II 48-P-550-0.80-K) (Product name : MR27V3202D-xxTA)

PIN CONFIGURATION (TOP VIEW)



PIN NAMES	FUNCTIONS
D15/A-1	Data output / Address input
A0-A20	Address input
D0-D14	Data output
\overline{CE}	Chip enable
\overline{OE}	Output enable
V_{CC}	Power supply voltage
V_{SS}	GND
\overline{BYTE}	Mode switch
NC	Non connection

BLOCK DIAGRAM



In 8-bit output mode, these pins are three-stated and pin D15 functions as the A-1 address pin.

FUNCTION TABLE

MODE	$\overline{\text{CE}}$	$\overline{\text{OE}}$	$\overline{\text{BYTE}}$	V_{CC}	D0 - D7	D8 - D14	D15/A-1
READ (16-Bit)	L	L	H	3.0V to 3.3V	D_{OUT}		
READ (8-Bit)	L	L	L		D_{OUT}	Hi-Z	L/H
OUTPUT DISABLE	L	H	H		Hi-Z		*
			L		Hi-Z		*
STAND-BY	H	*	H	Hi-Z		*	
			L	Hi-Z		*	

*: Don't Care

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Value	Unit
Operating temperature under bias	T_{opr}	-	0 to 70	°C
Storage temperature	T_{stg}		-55 to 125	°C
Input voltage	V_I	relative to V_{SS}	-0.5 to $V_{CC} + 0.5$	V
Output voltage	V_O		-0.5 to $V_{CC} + 0.5$	V
Power supply voltage	V_{CC}		-0.5 to 5	V
Power dissipation per package	P_D	-	1.0	W

RECOMMENDED OPERATING CONDITIONS

(Ta=0 to 70°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
V_{CC} power supply voltage	V_{CC}	$V_{CC}=2.7V-3.6V$	2.7	-	3.6	V
Input "H" level	V_{IH}		2.2	-	$V_{CC}+0.5^*$	V
Input "L" level	V_{IL}		-0.5**	-	0.6	V

Voltage is relative to V_{SS} * : $V_{CC}+1.5V$ (Max.) when pulse width of overshoot is less than 10nS.

** : -1.5V (Min.) when pulse width of undershoot is less than 10nS.

ELECTRICAL CHARACTERISTICS (Read operation)**DC Characteristics 1** $(V_{CC}=3V\pm 0.3V, T_a=0 \text{ to } 70^\circ\text{C})$

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I_{LI}	$V_I=0 \text{ to } V_{CC}$	-	-	10	μA
Output leakage current	I_{LO}	$V_O=0 \text{ to } V_{CC}$	-	-	10	μA
V_{CC} power supply current (Standby)	I_{CCSC}	$\overline{CE}=V_{CC}$	-	-	50	μA
	I_{CCST}	$\overline{CE}=V_{IH}$	-	-	1	mA
V_{CC} power supply current (Read)	I_{CCA}	$\overline{CE}=V_{IL}, \overline{OE}=V_{IH} \text{ } t_c=120\text{ns}$	-	-	35	mA
Input "H" level	V_{IH}	-	2.2	-	$V_{CC}+0.5^*$	V
Input "L" level	V_{IL}	-	-0.5**	-	0.6	V
Output "H" level	V_{OH}	$I_{OH}=-400\mu\text{A}$	2.4	-	-	V
Output "L" level	V_{OL}	$I_{OL}=2.1\text{mA}$	-	-	0.4	V

Voltage is relative to Vss

* : $V_{CC}+1.5\text{V}$ (Max.) when pulse width of overshoot is less than 10nS.** : -1.5V (Min.) when pulse width of undershoot is less than 10nS.**DC Characteristics 2** $(V_{CC}=3.3V\pm 0.3V, T_a=0 \text{ to } 70^\circ\text{C})$

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I_{LI}	$V_I=0 \text{ to } V_{CC}$	-	-	10	μA
Output leakage current	I_{LO}	$V_O=0 \text{ to } V_{CC}$	-	-	10	μA
V_{CC} power supply current (Standby)	I_{CCSC}	$\overline{CE}=V_{CC}$	-	-	50	μA
	I_{CCST}	$\overline{CE}=V_{IH}$	-	-	1	mA
V_{CC} power supply current (Read)	I_{CCA}	$\overline{CE}=V_{IL}, \overline{OE}=V_{IH} \text{ } t_c=100\text{ns}$	-	-	40	mA
Input "H" level	V_{IH}	-	2.2	-	$V_{CC}+0.5^*$	V
Input "L" level	V_{IL}	-	-0.5**	-	0.6	V
Output "H" level	V_{OH}	$I_{OH}=-400\mu\text{A}$	2.4	-	-	V
Output "L" level	V_{OL}	$I_{OL}=2.1\text{mA}$	-	-	0.4	V

Voltage is relative to Vss

* : $V_{CC}+1.5\text{V}$ (Max.) when pulse width of overshoot is less than 10nS.** : -1.5V (Min.) when pulse width of undershoot is less than 10nS.

AC Characteristics 1(V_{CC}=3V±0.3V, T_a=0 to 70°C)

Parameter	Symbol	Condition	Min.	Max.	Unit
Address cycle time	T _C	-	120	-	ns
Address access time	T _{ACC}	$\overline{CE}=\overline{OE}=V_{IL}$	-	120	ns
\overline{CE} access time	T _{CE}	$\overline{OE}=V_{IL}$	-	120	ns
\overline{OE} access time	T _{OE}	$\overline{CE}=V_{IL}$	-	30	ns
Output disable time	T _{CHZ}	$\overline{OE}=V_{IL}$	0	30	ns
	T _{OHZ}	$\overline{CE}=V_{IL}$	0	20	ns
Output hold time	T _{OH}	$\overline{CE}=\overline{OE}=V_{IL}$	0	-	ns

Measurement conditions

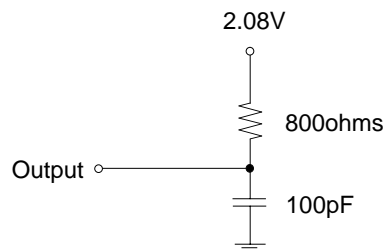
Input signal level	-----	0V/3V
Input timing reference level	-----	0.8V/2.0V
Output load	-----	100pF
Output timing reference level	-----	0.8V/2.0V

AC Characteristics 2(V_{CC}=3.3V±0.3V, T_a=0 to 70°C)

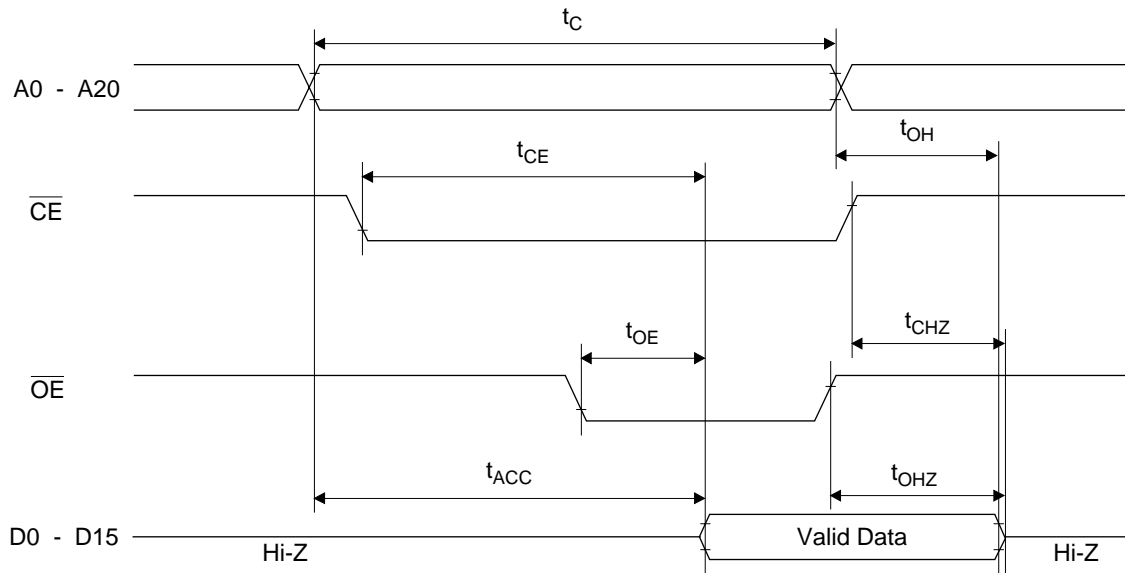
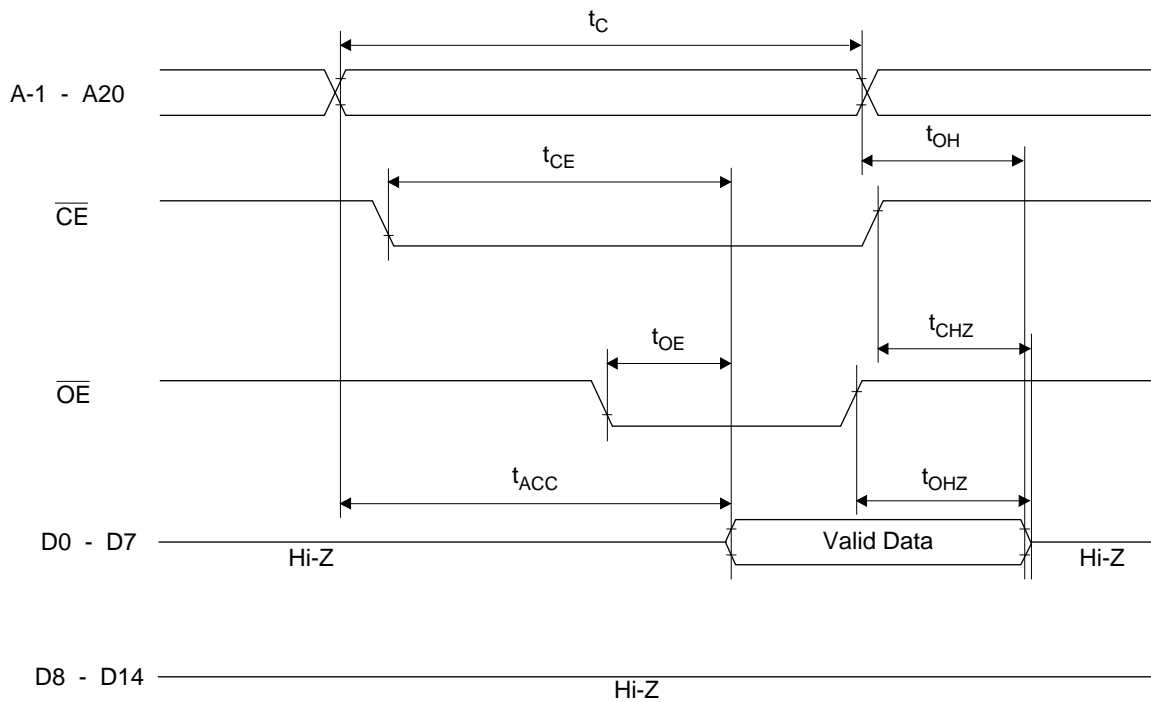
Parameter	Symbol	Condition	Min.	Max.	Unit
Address cycle time	T _C	-	100	-	ns
Address access time	T _{ACC}	$\overline{CE}=\overline{OE}=V_{IL}$	-	100	ns
\overline{CE} access time	T _{CE}	$\overline{OE}=V_{IL}$	-	100	ns
\overline{OE} access time	T _{OE}	$\overline{CE}=V_{IL}$	-	30	ns
Output disable time	T _{CHZ}	$\overline{OE}=V_{IL}$	0	30	ns
	T _{OHZ}	$\overline{CE}=V_{IL}$	0	20	ns
Output hold time	T _{OH}	$\overline{CE}=\overline{OE}=V_{IL}$	0	-	ns

Measurement conditions

Input signal level	-----	0V/3V
Input timing reference level	-----	0.8V/2.0V
Output load	-----	100pF
Output timing reference level	-----	0.8V/2.0V



TIMING CHART (READ CYCLE)

16-Bit Read Mode ($\overline{\text{BYTE}}=\text{V}_{\text{IH}}$)8-Bit Read Mode ($\overline{\text{BYTE}}=\text{V}_{\text{IL}}$)

PIN Capacitance $(V_{CC}=3.3V, T_a=25^{\circ}C, f=1MHz)$

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input	C_{IN1}	$V_I=0V$	-	-	8	pF
\overline{BYTE}	C_{IN2}		-	-	120	
Output	C_{OUT}	$V_O=0V$	-	-	10	